



1. G3 1.6um

1200V

100A @ Tc= 100

3.

4.

Product Name	V _{CES} (V)	I _c (A)	V _{GE(th)} (V)	V _{CE(sat)} (V)	V _F (V)	P _d (W)	T _j
DGQ100N120CTL2A	1200V	100A	5.8	1.5	2.00	883	-40~175

To-247PLUS 1200V

IGBT



Originals

1. 60V breakdown voltage, $I_{Tc} = 100A$
2. 200V breakdown voltage, $I_{Tc} = 100A$
3. Low conduction loss, suitable for low to mid frequency applications
4. Strong short-circuit capacity

Yangjie Technology recently launched a new generation of Q_{GTO}

New Product Announcement